

L Number	Hits	Search Text	DB	Time stamp
1	2522	((438/29) or (438/30) or (438/149) or (438/151) or (438/152)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:44
2	10815	black near2 matrix	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:44
3	142802	silicon near2 substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:49
7	39943	((cmp or (chemical adj mechanical)near2 polishing))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:50
9	0	((silicon near2 substrate) near ((cmp or (chemical adj mechanical)near2 polishing))) and (black near2 matrix)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:50
10	0	((((438/29) or (438/30) or (438/149) or (438/151) or (438/152)).CCLS.) and ((silicon near2 substrate) near ((cmp or (chemical adj mechanical)near2 polishing)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:51
8	54	((silicon near2 substrate) near ((cmp or (chemical adj mechanical)near2 polishing))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:53
11	1622	((tft or (thin adj film adj transistor) or transistor) near panel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:54
12	0	((silicon near2 substrate) near ((cmp or (chemical adj mechanical)near2 polishing))) and ((tft or (thin adj film adj transistor) or transistor) near panel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/13 16:54
-	25220	((tft or (thin adj film adj transistor) with panel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/07/10 11:31
-	2682	((tft or (thin adj film adj transistor) with panel)) with transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/07/10 11:32
-	73	((tft or (thin adj film adj transistor) with panel)) with transparent) with insulator	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/07/10 11:32
-	45	((tft or (thin adj film adj transistor) with panel)) with transparent) with insulator) with electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/07/10 11:41
-	4	((transparent adj substrate) with (silicon adj substrate)) with tft	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/07/10 11:42

102	(transparent adj substrate) with (silicon adj substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 15:55
0	((thin adj film adj transistor adj panel)) with ((transparent adj substrate) with (silicon adj substrate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:01
0	((thin adj film adj transistor adj panel)) and((transparent adj substrate) with (silicon adj substrate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:12
0	((thin adj film adj transistor adj panel)) with ((transparent adj substrate) and (silicon adj substrate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:10
213	(thin adj film adj transistor adj panel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:11
0	((thin adj film adj transistor adj panel)) and((transparent and silicon) adj substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:13
1	((thin adj film adj transistor adj panel)) with (transparent and silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:14
0	((thin adj film adj transistor adj panel)) with (transparent and (silicon adj substrate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:14
0	((thin adj film adj transistor adj panel)) and(transparent and (silicon adj substrate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:14
0	((thin adj film adj transistor adj panel)) with (silicon adj substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:15
31	((thin adj film adj transistor adj panel)) with transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 13:15
52	(transparent adj substrate) with (silicon adj substrate) and remove\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 15:56
19	(transparent adj substrate) with (silicon adj substrate) same remove\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 16:01
16235	(silicon adj substrate) same remove\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 16:02

14	{{(silicon adj substrate) same remove\$3} same transparent) same insulator	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 16:02
162	{{(silicon adj substrate) same remove\$3} same transparent	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/10 16:08
1	"6252300".PN.	USPAT; US-PGPUB	2002/07/10 16:11
1	"5985693".PN.	USPAT; US-PGPUB	2002/07/10 16:11
1	"5923067".PN.	USPAT; US-PGPUB	2002/07/10 16:12
1	"5880010".PN.	USPAT; US-PGPUB	2002/07/10 16:12
1	"5426072".PN.	USPAT; US-PGPUB	2002/07/10 16:13
2121	{{(438/29) or (438/30) or (438/149) or (438/151) or (438/152)}.CCLS.	USPAT; US-PGPUB	2003/11/13 16:43
0	{{(438/29) or (438/30) or (438/149) or (438/151) or (438/152)}.CCLS.	EPO; JPO; DERWENT; IBM TDB	2003/04/02 11:11
335508	bond	USPAT; US-PGPUB	2003/04/02 11:27
128580	silicon same substrate	USPAT; US-PGPUB	2003/04/02 11:28
7737	black with matrix	USPAT; US-PGPUB	2003/04/02 11:29
451	{{(438/29) or (438/30) or (438/149) or (438/151) or (438/152)}.CCLS.) and bond	USPAT; US-PGPUB	2003/04/02 11:29
397	{{(438/29) or (438/30) or (438/149) or (438/151) or (438/152)}.CCLS.) and bond)	USPAT; US-PGPUB	2003/04/02 11:29
32	and (silicon same substrate) and (((438/29) or (438/30) or (438/149) or (438/151) or (438/152)}.CCLS.) and bond) and (silicon same substrate)) and (black with matrix)	USPAT; US-PGPUB	2003/04/02 11:37
10	("5008218" "5468521" "5527649" "5589962" "5693541" "5747121" "5767930" "5807772" "5888839" "5926735").PN.	USPAT	2003/04/02 11:34
2	6127199.URPN.	USPAT	2003/04/02 11:35
805814	remove	USPAT; US-PGPUB	2003/04/02 11:37
10558	remove same (silicon same substrate)	USPAT; US-PGPUB	2003/04/02 11:37
188	{{(438/29) or (438/30) or (438/149) or (438/151) or (438/152)}.CCLS.) and (remove same (silicon same substrate))	USPAT; US-PGPUB	2003/04/02 11:38
8	{{(438/29) or (438/30) or (438/149) or (438/151) or (438/152)}.CCLS.) and (remove same (silicon same substrate)) and (black with matrix)	USPAT; US-PGPUB	2003/04/02 11:38